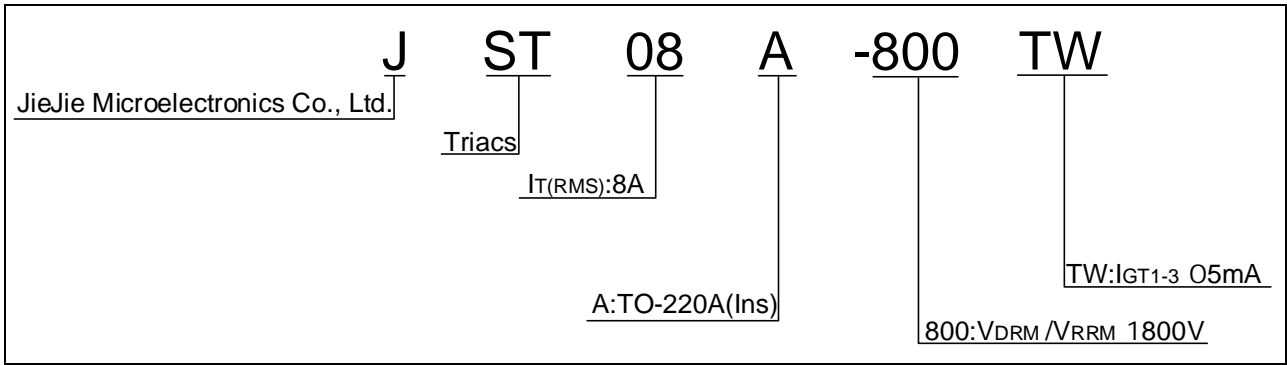


Peak gate current ($t_p=20 \text{ s}$, $T_j=125 \text{ }^\circ\text{C}$)

I_{GM}

4

ORDERING INFORMATION



MARKING

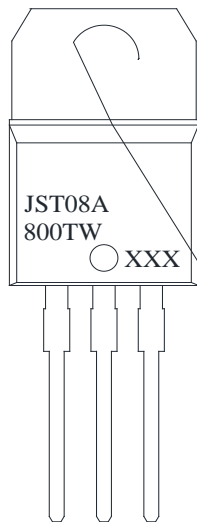


FIG.1: Maximum power dissipation versus RMS on-state current

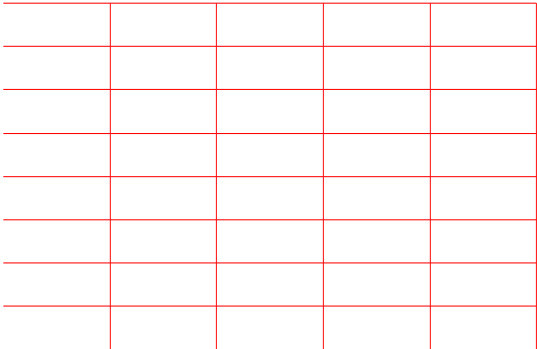
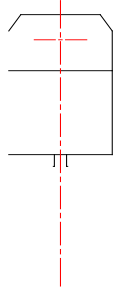


FIG.2: RMS on-state current versus case temperature



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